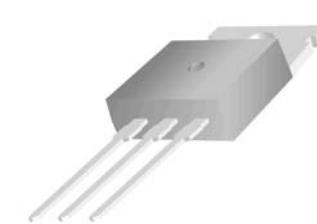
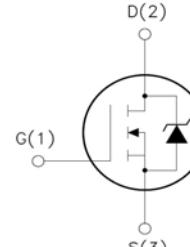


140N10 Features: <ul style="list-style-type: none"> <input type="checkbox"/> Low Intrinsic Capacitances. <input type="checkbox"/> Excellent Switching Characteristics. <input type="checkbox"/> Extended Safe Operating Area. <input type="checkbox"/> Unrivalled Gate Charge :$Q_g = 126.7\text{nC}$ (Typ.). <input type="checkbox"/> $\text{BVDSS}=100\text{V}, \text{I}_D=140\text{A}$ <input type="checkbox"/> $\text{R}_{DS(\text{on})} : 7.2\text{m}\Omega$ (Max) @ $\text{V}_G=10\text{V}$ <input type="checkbox"/> 100% Avalanche Tested 	<div style="text-align: center;"> TO-220    <p>1.Gate (G) 2.Drain (D) 3.Source (S)</p> </div>
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Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Maximum	Unit
V_{DSS}	Drain-to-Source Voltage	100	V
V_{GSS}	Gate-to-Source Voltage	± 25	V
I_D^3	Continuous Drain Current	$T_C=25^\circ\text{C}$	140
		$T_C=100^\circ\text{C}$	97
I_{DP}^4	Pulsed Drain Current	$T_C=25^\circ\text{C}$	530
I_{AS}^5	Avalanche Current	33	
E_{AS}^5	Avalanche energy	560	mJ
PD	Maximum Power Dissipation	$T_C=25^\circ\text{C}$	215
		$T_C=100^\circ\text{C}$	105
T_J, T_{STG}	Junction & Storage Temperature Range	-55~175	°C

Thermal Characteristics

Symbol	Parameter	Typical	Unit
$R_{\theta jc}$	Thermal Resistance-Junction to Case	0.68	°C/W
$R_{\theta ja}$	Thermal Resistance-Junction to Ambient	62.5	

Electrical Characteristics (TA=25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Typ	Max.	Unit
Static Characteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	100	—	—	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =80V, V _{GS} =0V	—	—	1	uA
		T _J =125°C	—	—	20	
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	2	3	4	V
I _{GSS}	Gate Leakage Current	V _{GS} =±25V, V _{DS} =0V	—	—	±100	nA
R _{DS(on)} ¹	Drain-Source On-Resistance	V _{GS} =10V, I _D =60A	—	6.2	7.2	mΩ
		—	—	—	—	
Diode Characteristics						
V _{SD} ¹	Diode Forward Voltage	I _{SD} =60A, V _{GS} =0V	—	0.8	1.3	V
I _S ³	Diode Continuous Forward Current	—	—	50	—	A
t _{rr}	Reverse Recovery Time	I _F =60A, V _{DD} =50V	—	65	—	nS
Q _{rr}	Reverse Recovery Charge	dl/dt=100A/us	—	102	—	nC
Dynamic Characteristics²						
R _G	Gate Resistance	V _{GS} =0V, V _{DS} =0V, Frequency=1MHz	—	1.8	—	Ω
C _{iss}	Input Capacitance	V _{GS} =0V, V _{DS} =25V Frequency=1MHz	—	6235	—	pF
C _{oss}	Output Capacitance		—	942	—	
C _{rss}	Reverse Transfer Capacitance		—	506	—	
t _{d(on)}	Turn-On Delay Time	V _{DD} =50V, I _D =30A, V _{GS} =10V, R _G =25Ω	—	51	—	nS
t _r	Rise Time		—	116	—	
t _{d(off)}	Turn-Off Delay Time		—	247	—	
t _f	Fall Time		—	150	—	
Gate Charge Characteristics²						
Q _g	Total Gate Charge	V _{DS} =80V, V _{GS} =10V I _D =30A	—	126.7	—	nC
Q _{gs}	Gate-to-Source Charge		—	20	—	
Q _{gd}	Gate-to-Drain Charge		—	55.5	—	

Note: 1: Pulse test; pulse width \leq 300us, duty cycle \leq 2%.

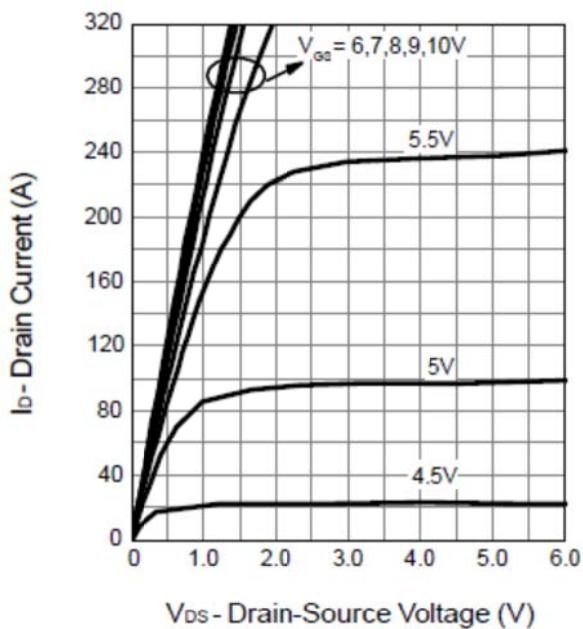
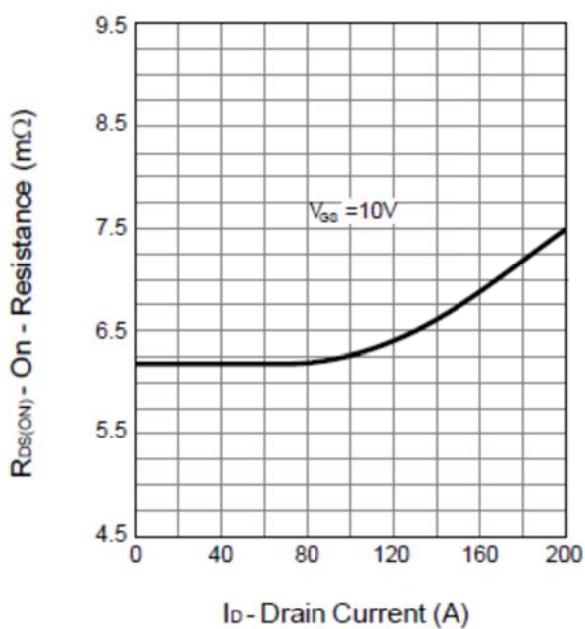
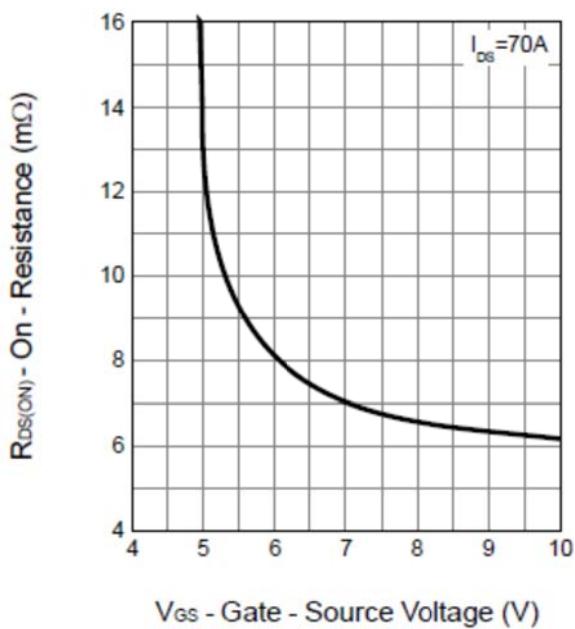
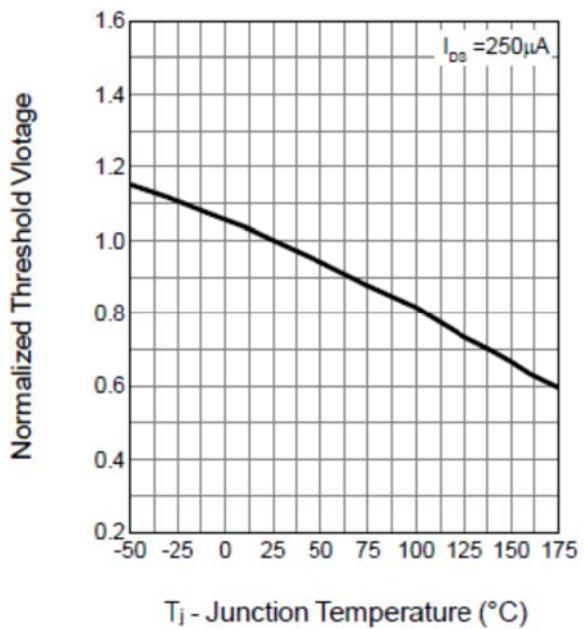
2: Guaranteed by design, not subject to production testing.

3: Package limitation current is 50A.Calculated continuous current based on maximum allowable junction temperature.

4: Repetitive rating, pulse width limited by max junction temperature.

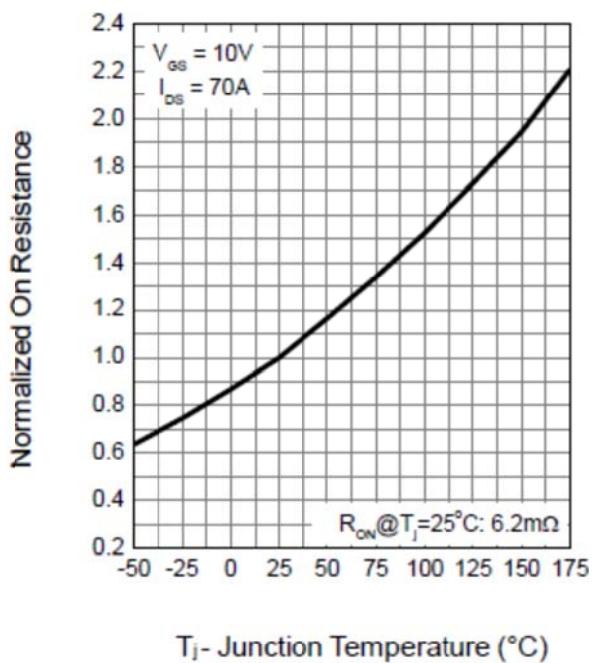
5: Starting TJ = 25°C,L = 0.5mH,VDD=90V. Ias=66A

Typical Characteristics

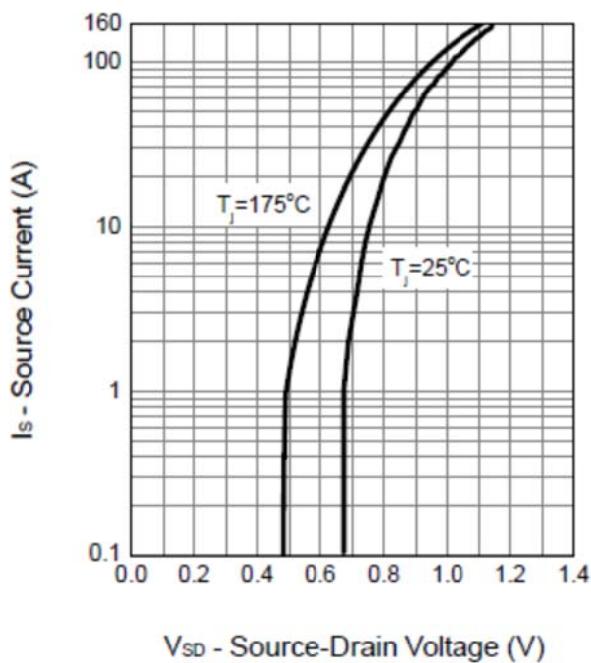
Output Characteristics

Drain-Source On Resistance

Drain-Source On Resistance

Gate Threshold Voltage


Typical Characteristics (Continued)

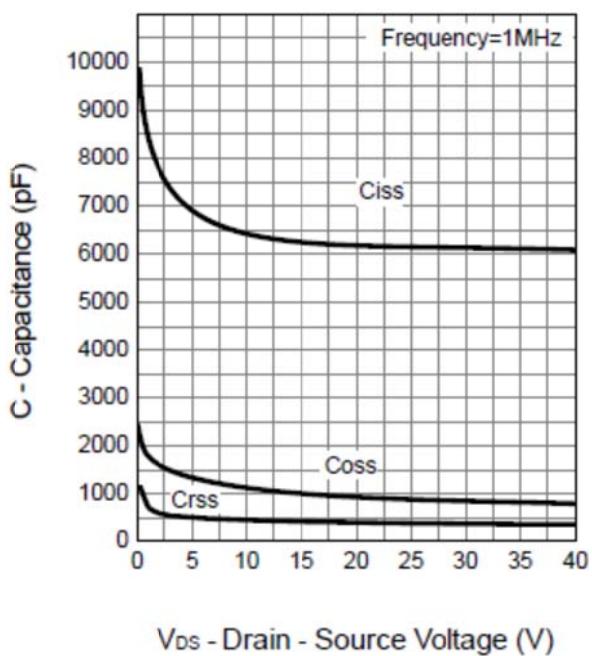
Drain-Source On Resistance



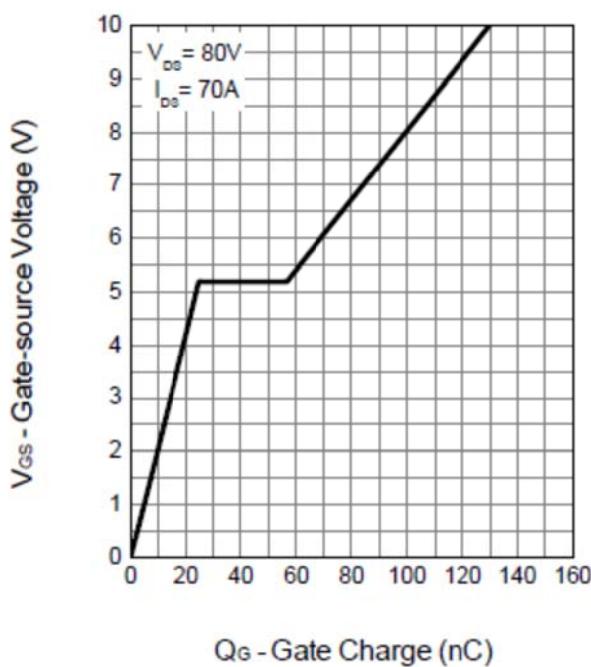
Source-Drain Diode Forward



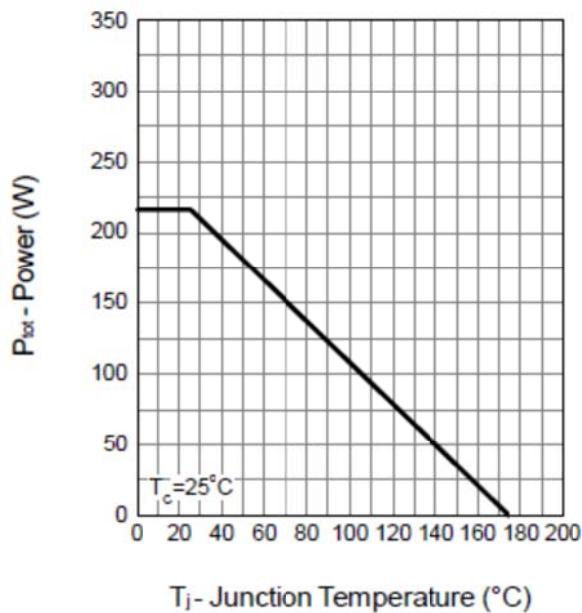
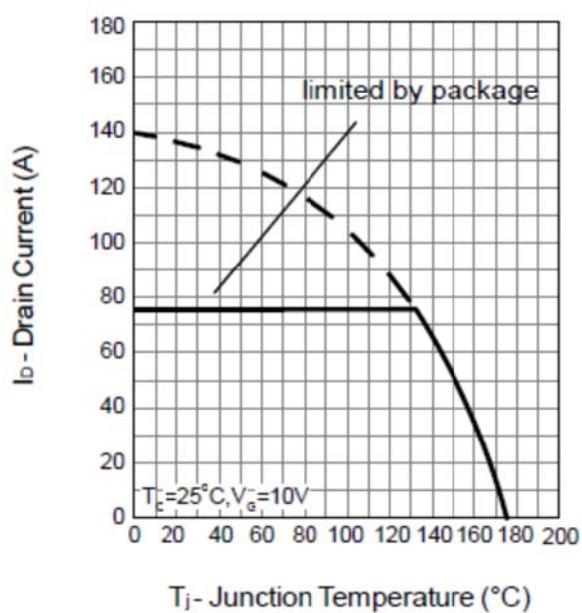
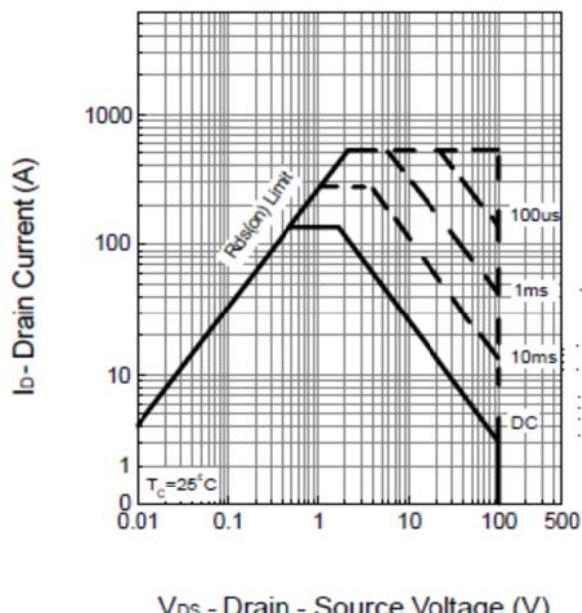
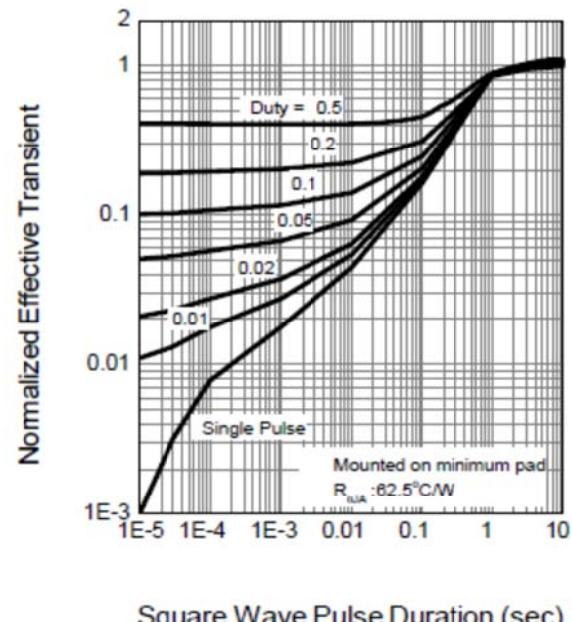
Capacitance



Gate Charge

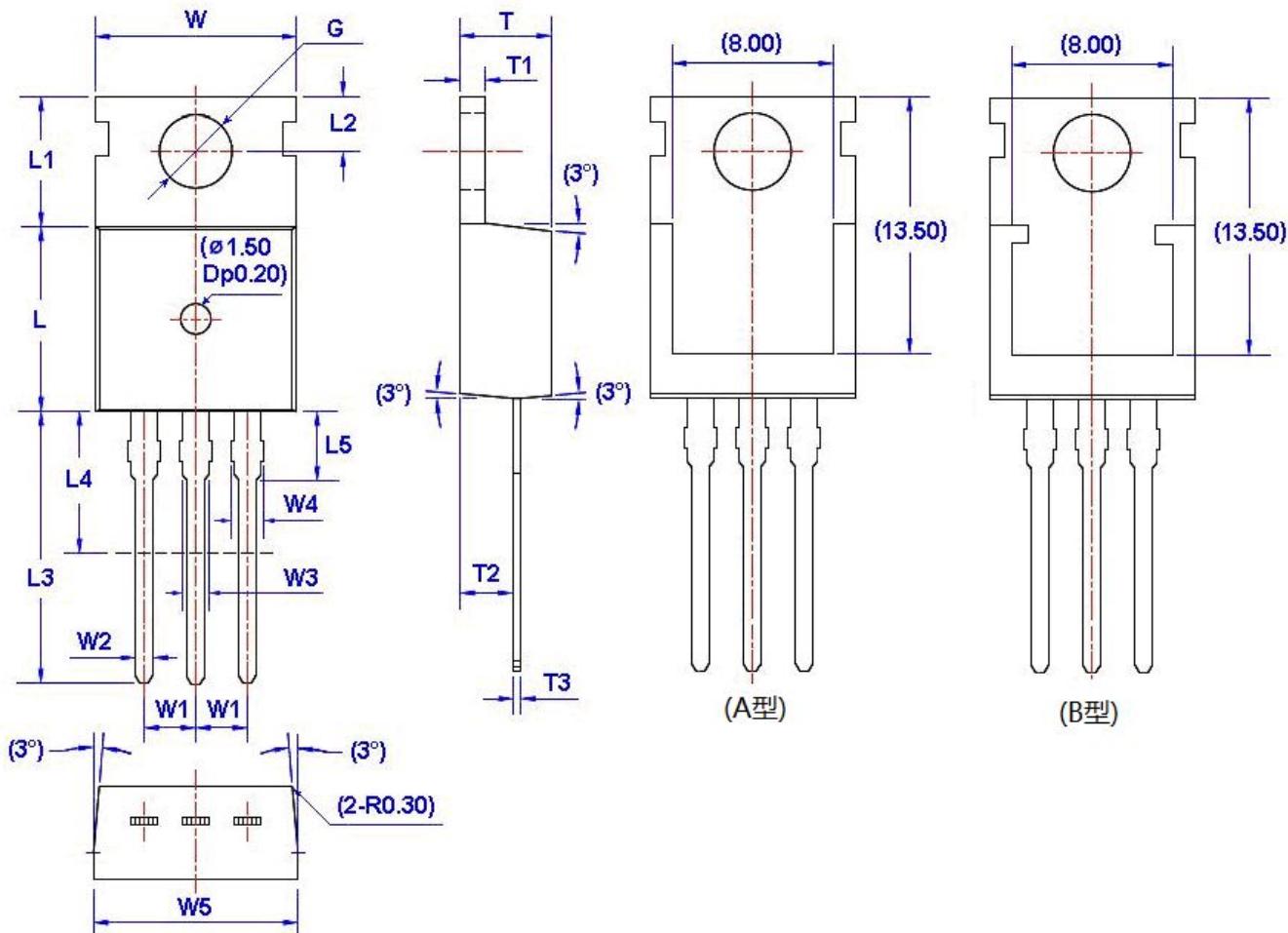


Typical Characteristics (Continued)

Power Dissipation

Drain Current

Safe Operation Area

Thermal Transient Impedance


Package Dimension

TO-220



符号	尺寸		符号	尺寸		符号	尺寸		符号	尺寸	
	Min	Max		Min	Max		Min	Max		Min	Max
W	9.66	10.28	W5	9.80	10.20	L4**	6.20	6.60	T3	0.45	0.60
W1	2.54 (TYP)		L	9.00	9.40	L5	2.79	3.30	G(Φ)	3.50	3.70
W2	0.70	0.95	L1	6.40	6.80	T	4.30	4.70			
W3	1.17	1.37	L2	2.70	2.90	T1	1.15	1.40			
W4*	1.32	1.72	L3	12.70	14.27	T2	2.20	2.60			